NSN 5961-01-115-9559

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-115-9559 **Inclosure Material:** Metal **Overall Length:** Between 1.248 inches and 1.252 inches **Overall Height:** Between 0.610 inches and 0.820 inches Overall Width: 0.700 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 collector to emitter voltage/static/base open and 4.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 4.00 amperes source cutoff current **Power Rating Per Characteristic:** 40.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:**

No

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